

FEA-Based Vibrational Analysis of the Inner Barrel Layers (L0–L1) in the SVT Detector

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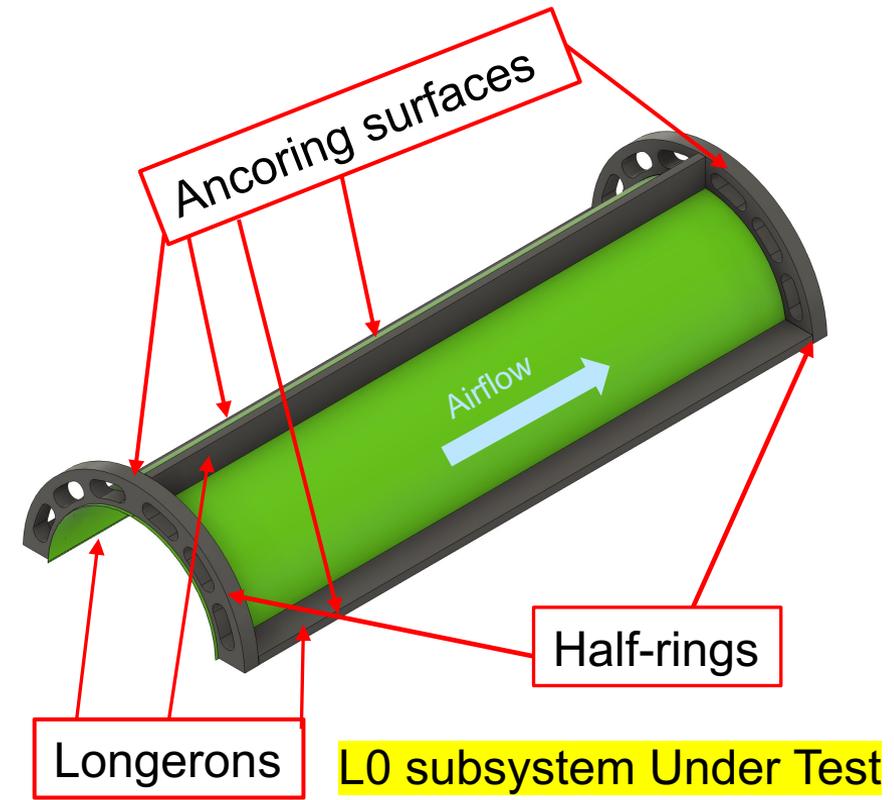
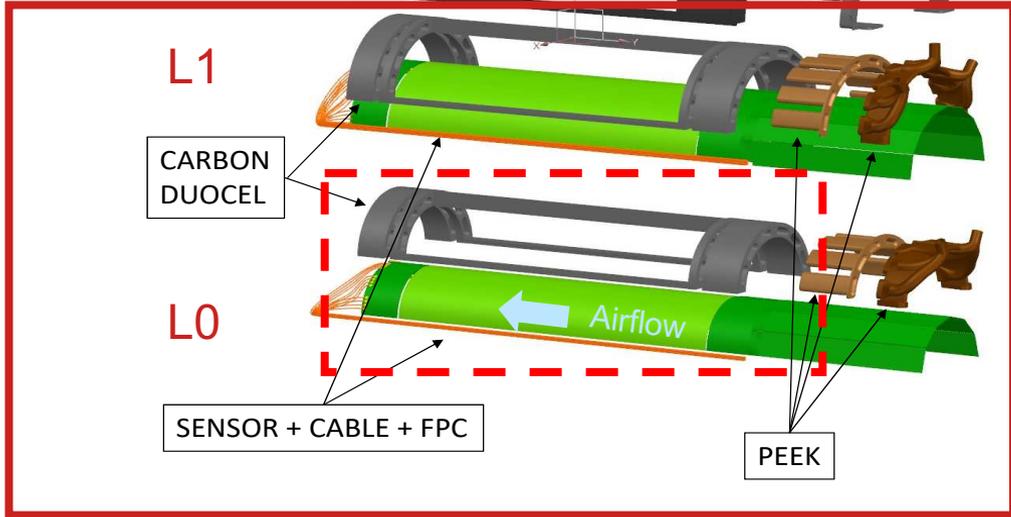
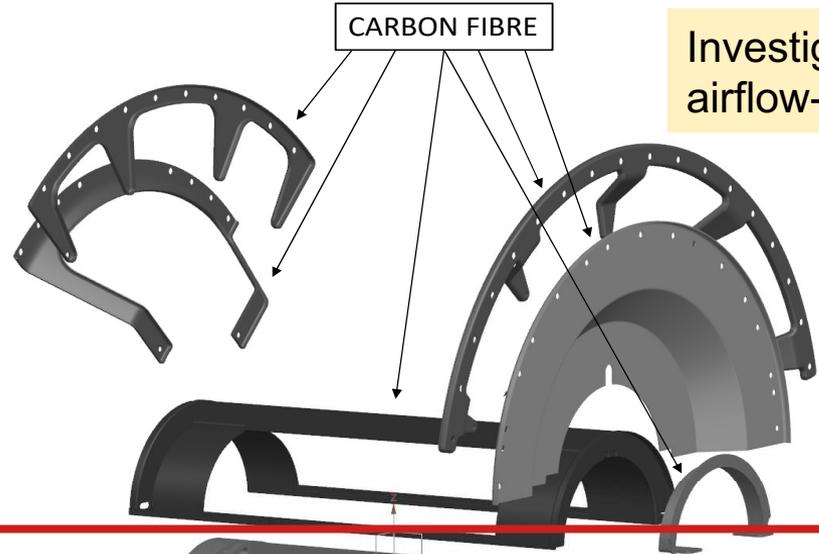


Outline:

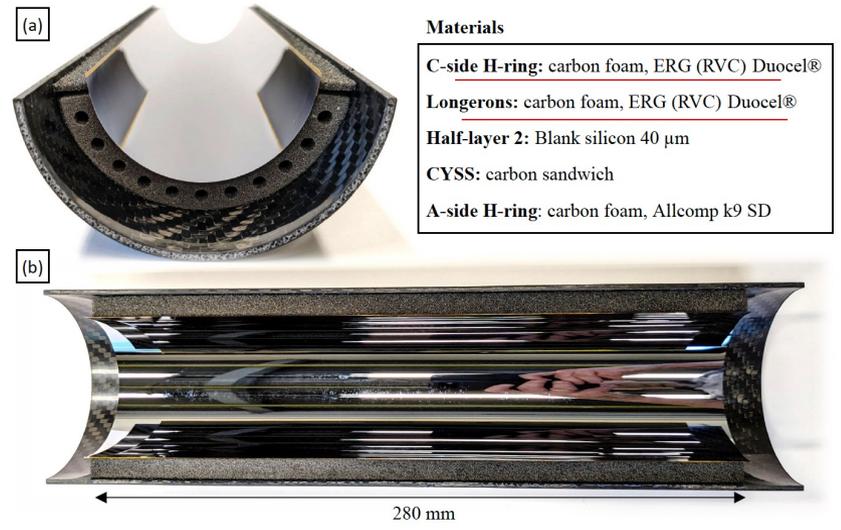
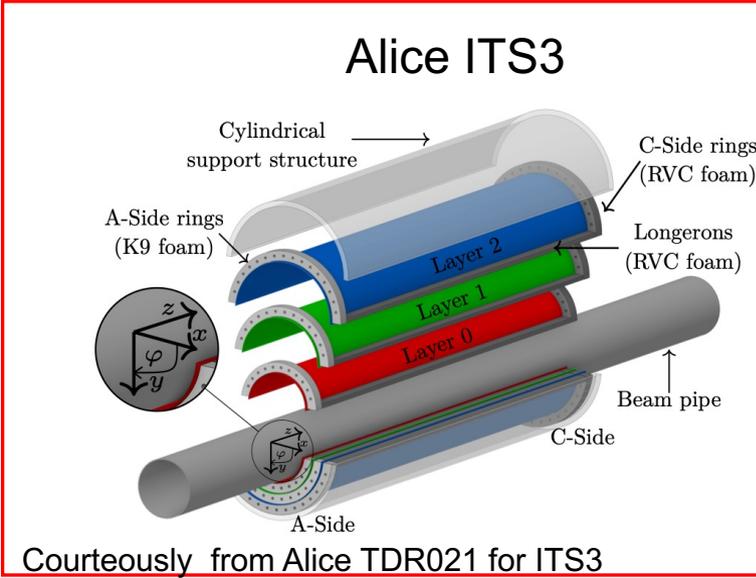
- Structural modeling of the L0–L1 SVT assembly (geometry and materials)
- Representation of the silicon layers as circular cylindrical shells with simply supported or clamped edges
- Validation of finite element model (FEM) results
- Realistic modal analysis of the L0–L1 SVT assembly
- PSD-based random vibration testing
- Conclusions and prospects

Structural modelling of the L0-L1 SVT assembly

Investigation of SVT vibrations due to multiple sources: airflow-induced, environment & thermal induced vibrations

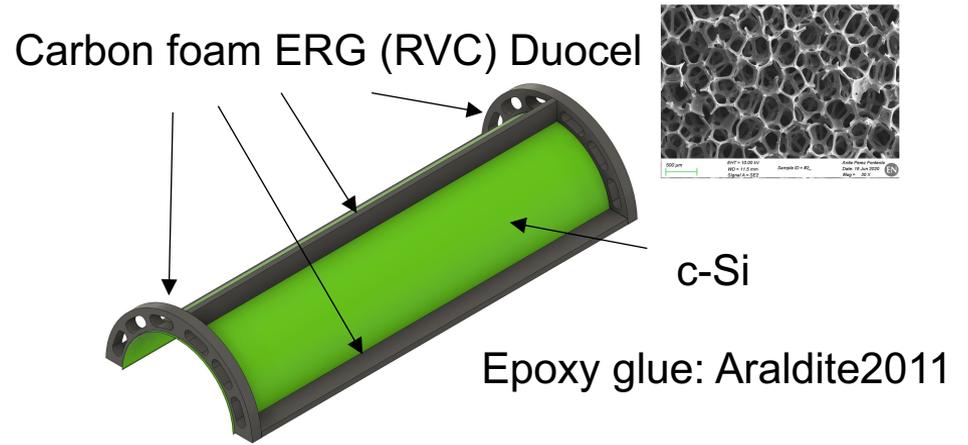


Materials & detector assembly



Shared challenge with ALICE- ITS3: minimum material budget achieved by a thin carbon cylindrical exoskeleton for the support of the three half-layers

Radius/Longitudinal/ contact angle	
R_{0iC}	38.15 [mm]
R_{0iG}	38.05 [mm]
R_{0iSi}	38.00 [mm]
L_{Si}	251.3 [mm]
L_{TOT}	264.00 [mm]
α_c	3.65°



Towards the mechanical characterisation of SVT

- 1- *Potential failure and evaluate the short-term/long-term reliability of SVT*
- 2- *Position stability of the sensor over time.*

With ref. TDR021 for ITS3

Short-term displacement is induced by air flow of the cooling system, the seismic (<1 Hz) and cultural noise (>1 Hz), and thermoelastic expansion caused by short-term temperature fluctuation.

$$\text{RMS}_{\text{tot}} = \sqrt{\text{RMS}_{\text{air flow}}^2 + \text{RMS}_{\text{noise}}^2 + \text{RMS}_{\Delta T}^2} < 1 \mu\text{m}$$

Aero-elasticity

Elasticity

Thermo-elasticity

Simulation FEM Workflow supporting experimental activity:

- LES Simulations – Incompressible Navier-Stokes fluid

Evaluate static and fluctuating pressure fields on L0–L1 layers to estimate aerodynamic loads.

- Harmonic Simulations – Transfer Function – PSD random vibrations

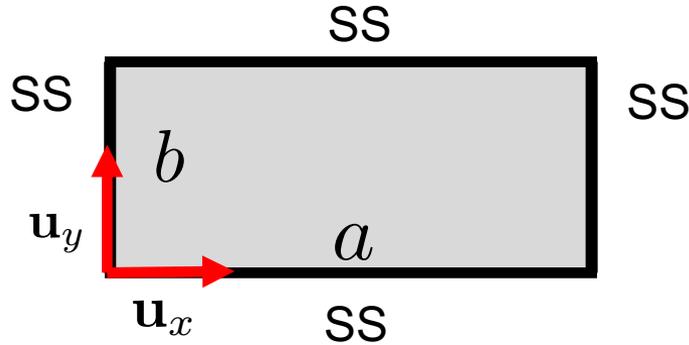
Assess how external acoustic excitations are transmitted to the L0–L1 layers.

- Transient Thermo-Structural Analysis

Analyse displacement evolution on L0–L1 layers due to thermal gradients with materials with different Coefficients of Thermal Expansion (CTEs).

Modelling of Si layers: circular cylindrical shells

Simply-supported plate

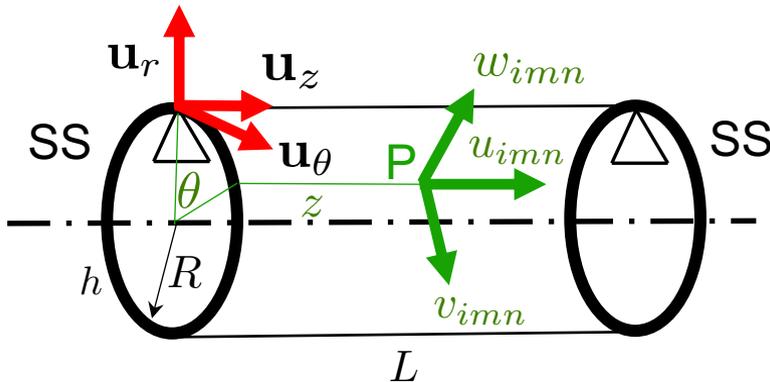


Natural frequencies & mode shape

$$D\nabla^2 w + \rho h \frac{\partial^2 w}{\partial t^2} = 0 \quad \omega_{mn} = \left(\left(\frac{m\pi}{a} \right)^2 + \left(\frac{n\pi}{b} \right)^2 \right) \sqrt{\frac{D}{\rho h}}$$

$$w(x, y, t) = \sum_m \sum_n C_{mn} \sin\left(\frac{m\pi x}{a}\right) \sin\left(\frac{n\pi y}{b}\right) \cos(\omega_{mn} t)$$

Simply-supported cylindrical shell



Mode shape function for the cylindrical shell

$$\begin{aligned} u_z(0, \theta, t) &= 0 \\ u_\theta(0, \theta, t) &= 0 \\ M_{zz}(0, \theta, t) &= 0 \\ N_{zz}(0, \theta, t) &= 0 \\ u_r(L, \theta, t) &= 0 \\ u_\theta(L, \theta, t) &= 0 \\ M_{zz}(L, \theta, t) &= 0 \\ N_{zz}(L, \theta, t) &= 0 \end{aligned}$$

$$\begin{aligned} u_{imn}(z, \theta, t) &= A_{imn} \cos \frac{m\pi z}{L} \cos(n\theta - \phi) \cos(\omega_{imn} t) \\ v_{imn}(z, \theta, t) &= B_{imn} \sin \frac{m\pi z}{L} \sin(n\theta - \phi) \cos(\omega_{imn} t) \\ w_{imn}(z, \theta, t) &= C_{imn} \sin \frac{m\pi z}{L} \cos(n\theta - \phi) \cos(\omega_{imn} t) \end{aligned}$$

For every (m,n) we have three frequencies $i=1,2,3$

m - longitudinal index
n - radial index

Ref. Vibrations of Shells and Plates
Werner Soedel

Cylindrical shell simply supported at the edges – approximation D-M-V

To understand the vibrational behaviours of the cylinder shell, we consider the Donnell–Mushtari–Vlasov approximation (shallow shell equations). Closed form is useful for mode identification following the approach of D–M–V with the guess function:

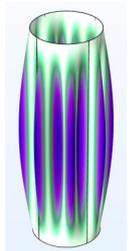
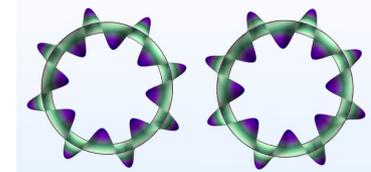
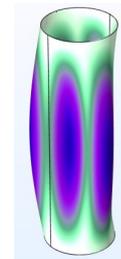
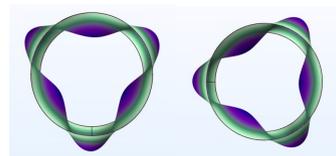
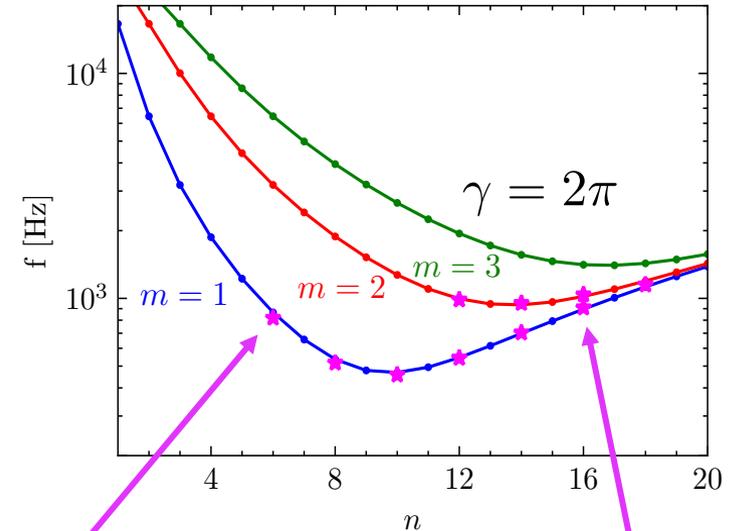
$$\tilde{w}_{mn}(z, \theta) = \sin \frac{m\pi z}{L} \cos\left(\frac{n(\theta - \phi)}{2}\right)$$

$$\omega_{mn} = \frac{1}{R} \sqrt{\frac{(m\pi R/L)^4}{[(m\pi R/L)^2 + (n/2)^2]^2} + \frac{(h/R)^2}{12(1-\nu^2)} \left[\left(\frac{m\pi R}{L}\right)^2 + \left(\frac{n}{2}\right)^2 \right]^2} \sqrt{\frac{Y}{\rho}}$$

Membrane stiffness

Bending stiffness

Analytical vs FEM



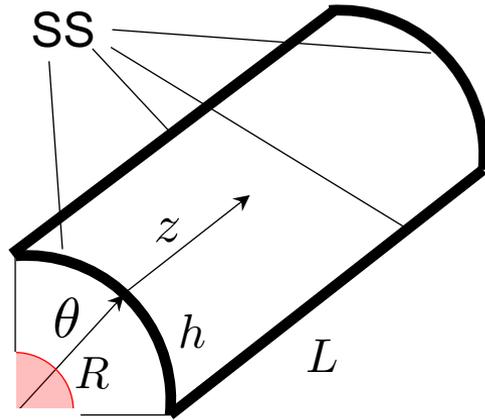
Cylindrical panel simply supported at all edges 1

General solution

$$u_{imn}(z, \theta, t) = A_{imn} \cos \frac{m\pi z}{L} \sin\left(\frac{n\pi\theta}{\gamma}\right) \cos(\omega_{imn}t)$$

$$v_{imn}(z, \theta, t) = B_{imn} \sin \frac{m\pi z}{L} \cos\left(\frac{n\pi\theta}{\gamma}\right) \cos(\omega_{imn}t)$$

$$w_{imn}(z, \theta, t) = C_{imn} \sin \frac{m\pi z}{L} \sin\left(\frac{n\pi\theta}{\gamma}\right) \cos(\omega_{imn}t)$$



$$\gamma = \pi/2$$

Donnell–Mushtari–Vlasov approximation with guess function:

$$\tilde{w}_{mn}(z, \theta) = \sin \frac{m\pi z}{L} \sin\left(\frac{n\pi\theta}{\gamma}\right)$$

Two additional BCs

$$u_r(z, 0, t) = 0 \quad u_r(z, \gamma, t) = 0$$

$$u_z(z, 0, t) = 0 \quad u_z(z, \gamma, t) = 0$$

$$M_{\theta\theta}(z, 0, t) = 0 \quad M_{\theta\theta}(z, \gamma, t) = 0$$

$$N_{\theta\theta}(z, 0, t) = 0 \quad N_{\theta\theta}(z, \gamma, t) = 0$$

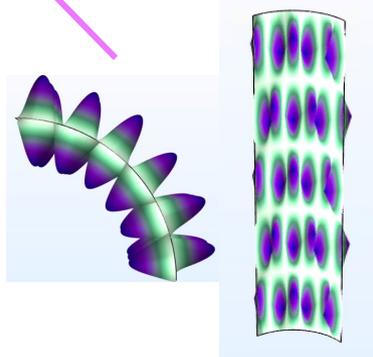
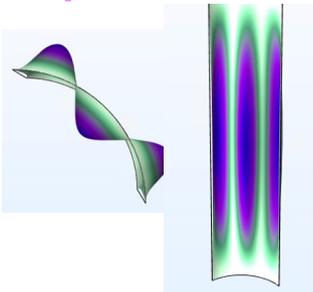
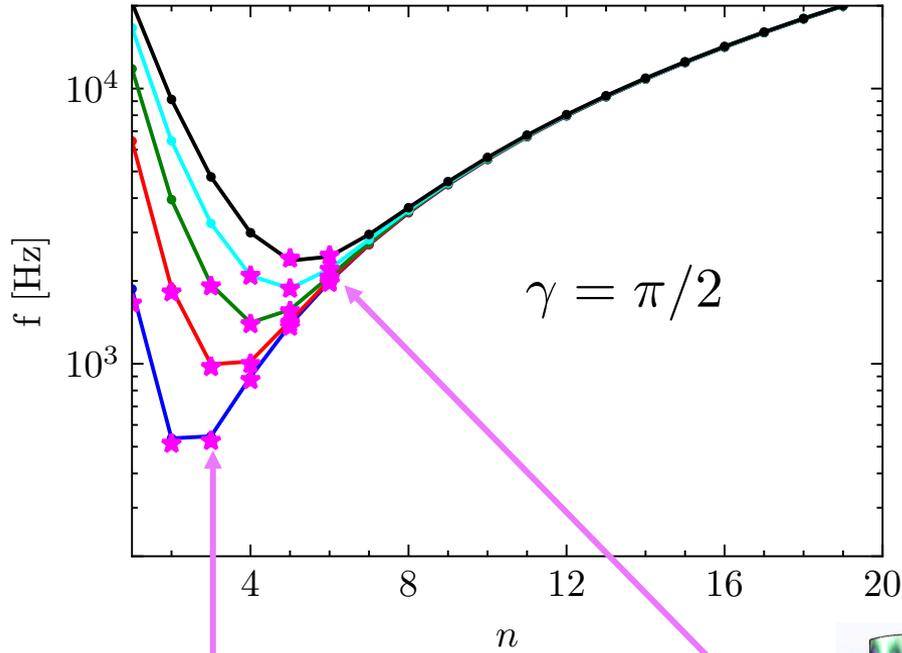
$$\omega_{mn} = \frac{1}{R} \sqrt{\underbrace{\frac{(m\pi R/L)^4}{[(m\pi R/L)^2 + (n\pi/\gamma)^2]^2}}_{\text{Membrane stiffness}} + \underbrace{\frac{(h/R)^2}{12(1-\nu^2)} \left[\left(\frac{m\pi R}{L}\right)^2 + \left(\frac{n\pi}{\gamma}\right)^2 \right]^2}_{\text{Bending stiffness}}} \sqrt{\frac{Y}{\rho}}$$

Membrane stiffness

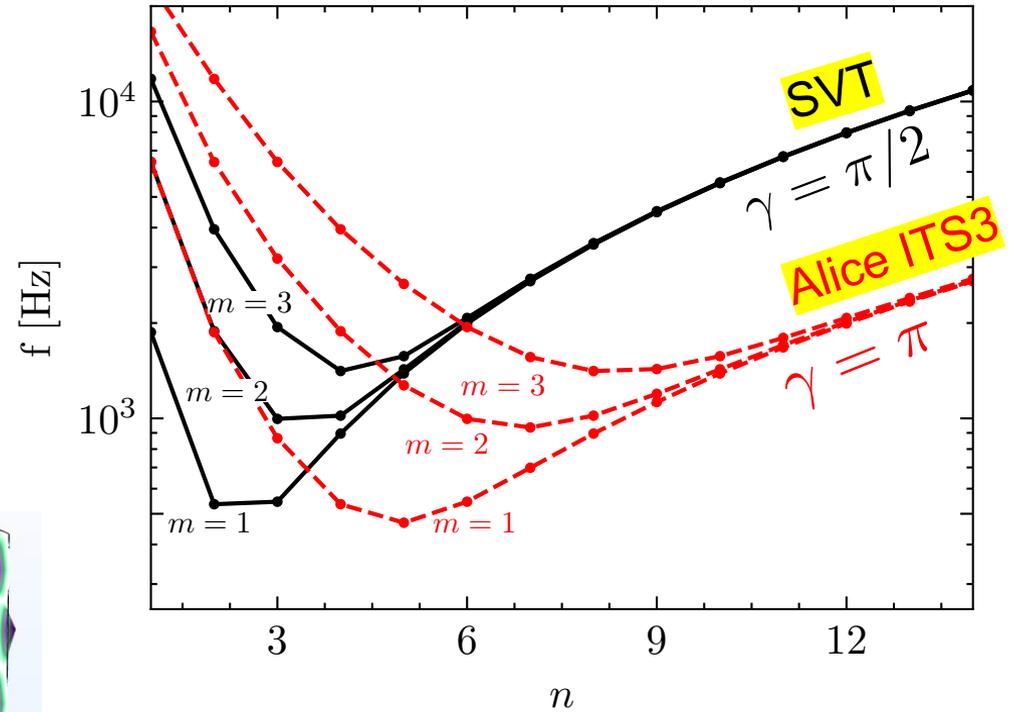
Bending stiffness

Cylindrical panel simply supported at all edges 2

Analitical vs FEM

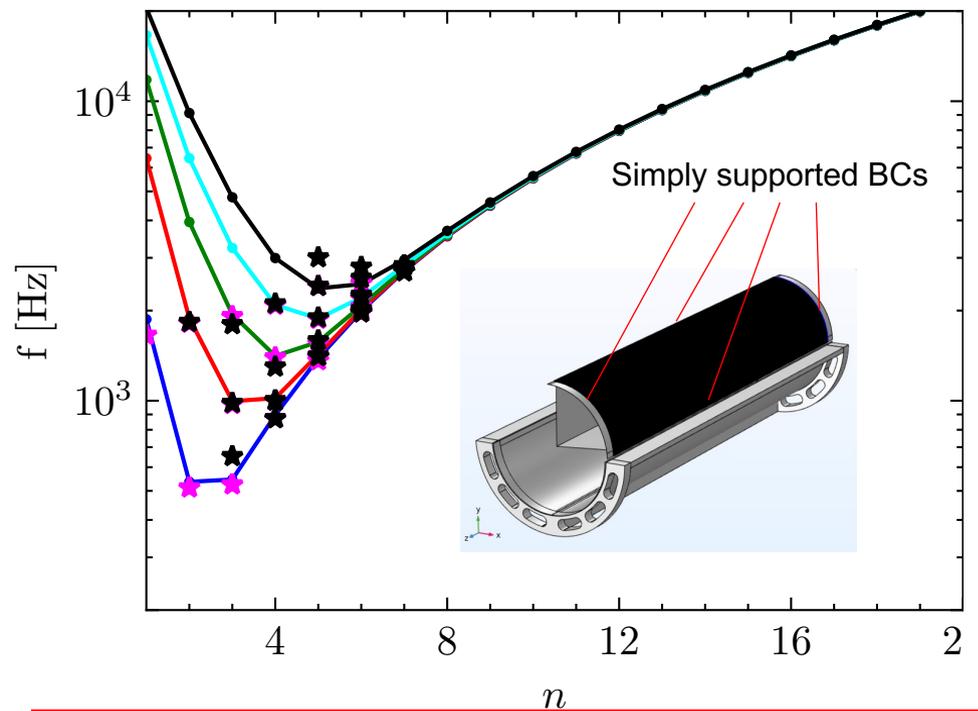


Comparison between two half layers

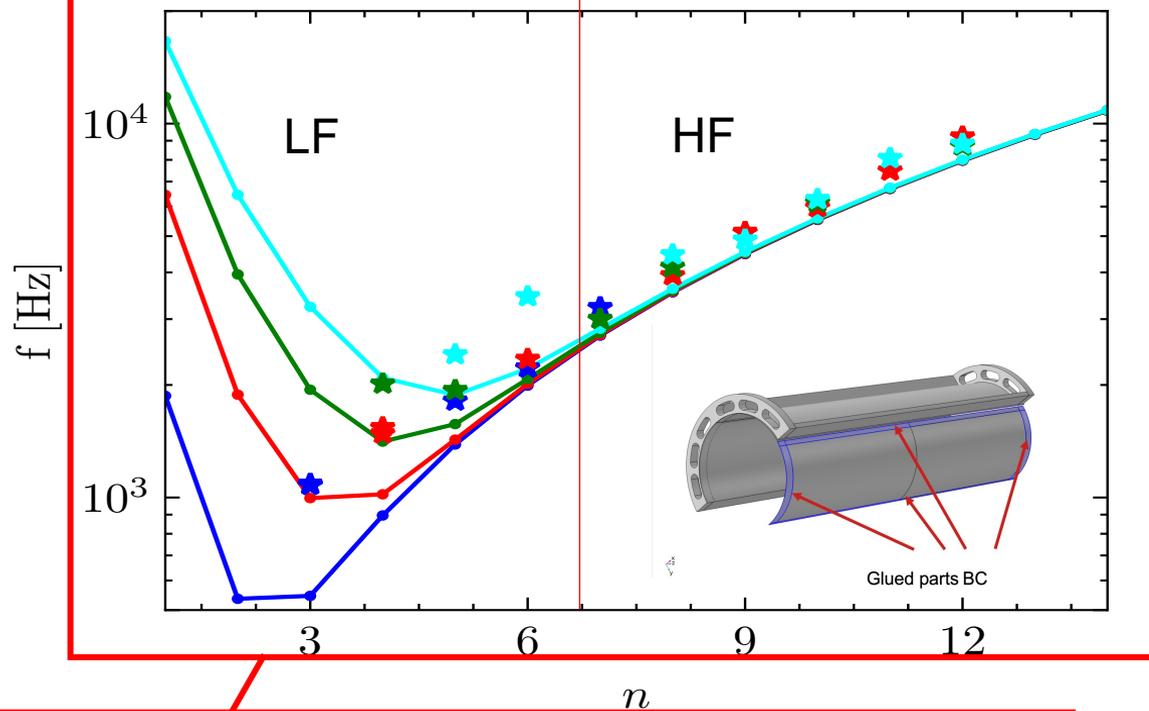


Modal analysis with two BCs of the SVT-L0 model

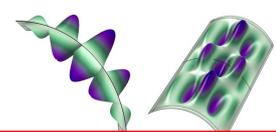
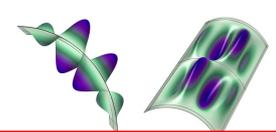
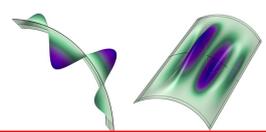
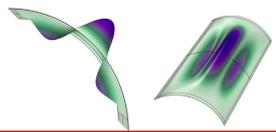
Simply- Supported FEM analysis



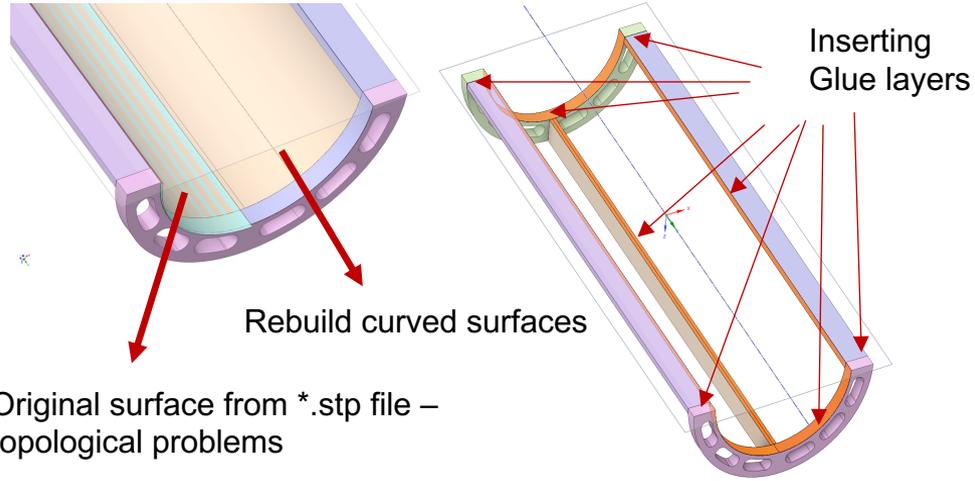
Built-in edges



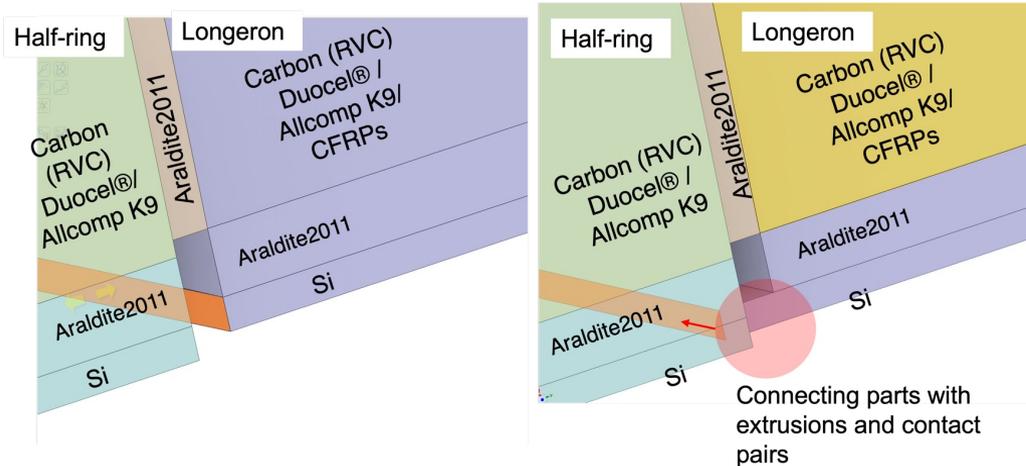
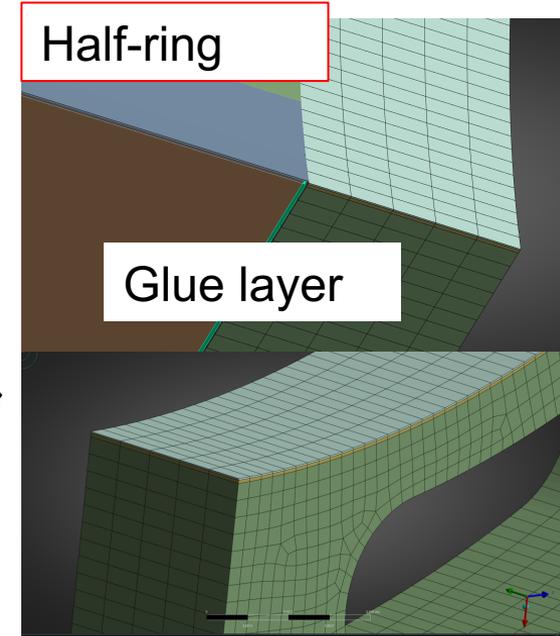
$1079.25[Hz] (m = 1, n = 3)$
 $1268.01[Hz] (m = 1, n = 4)$
 $1550.11[Hz] (m = 2, n = 4)$
 $1936.62[Hz] (m = 3, n = 5)$



CAD modelling & mesh strategy of the SVT-L0



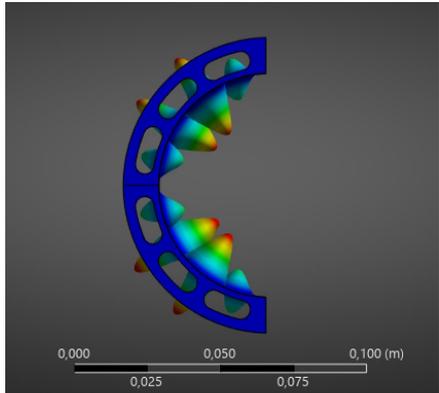
Original surface from *.stp file – topological problems



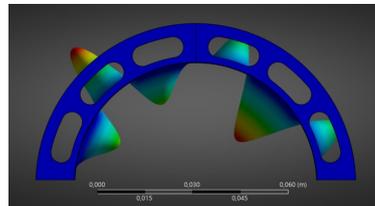
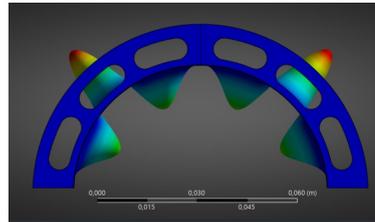
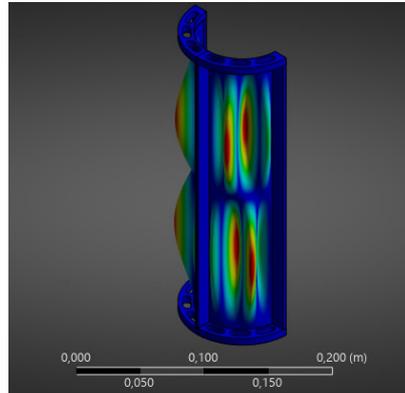
Mesh sweeping to obtain a regular and a good mesh quality.

Fully constrained half-layer SVT-L0 model

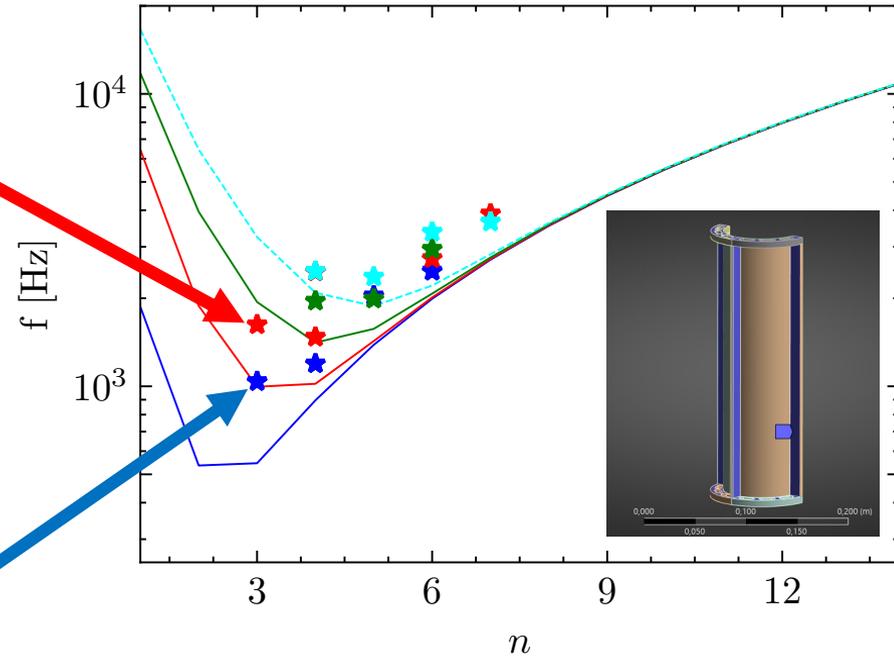
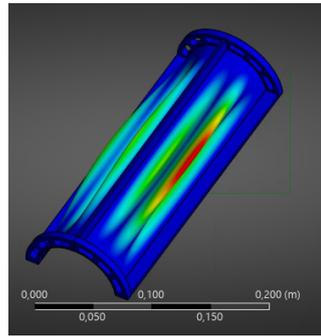
Analytical SS – Ansys FEM Build-in edges



$1624.00 [Hz] (m = 2, n = 4)$

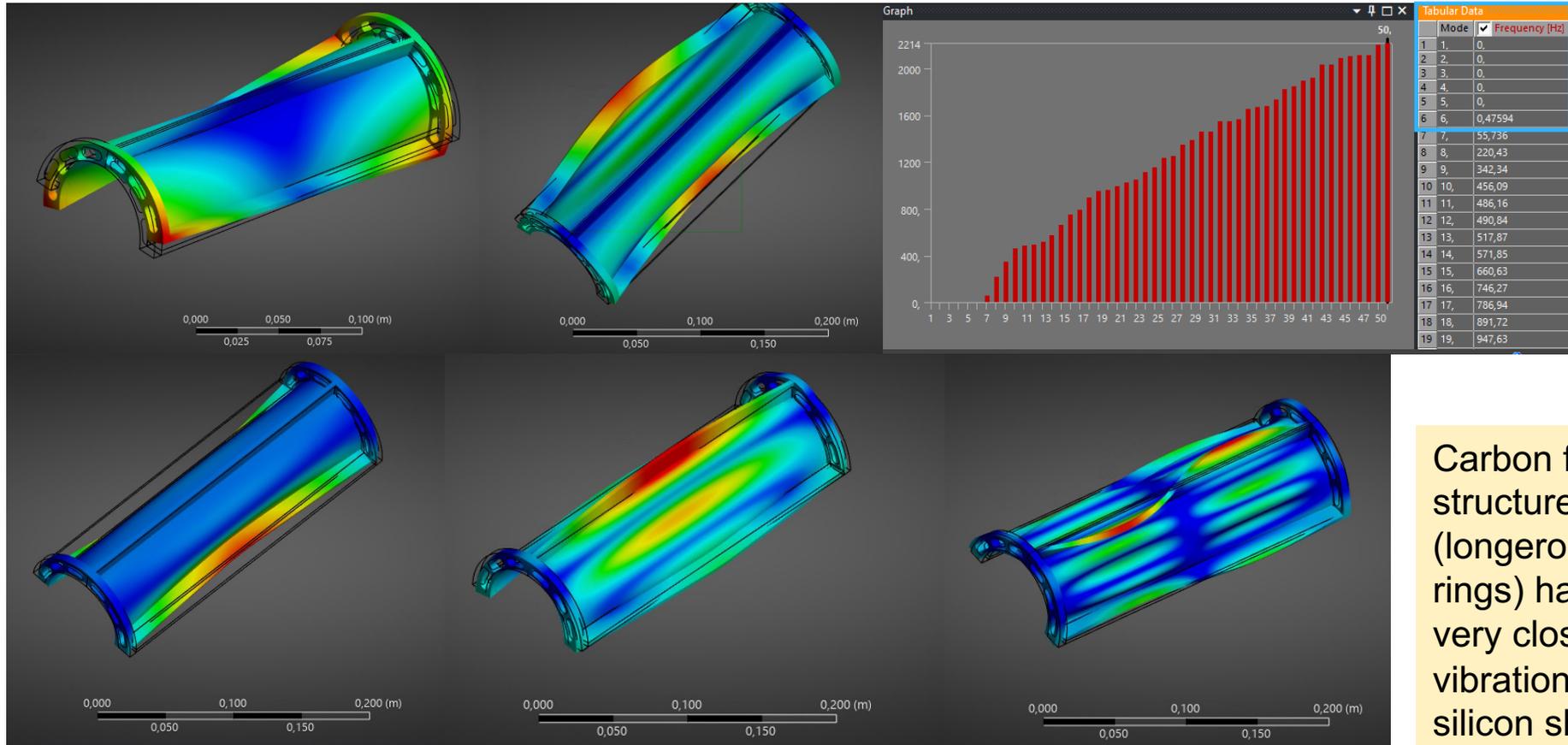


$1036.5 [Hz] (m = 1, n = 3)$



At low frequencies, increasing the number of radial nodes (n) raises the mode frequency. For higher n , frequencies become less sensitive to longitudinal boundary conditions, similar to a supported case. Additional mode shapes (not shown) contribute similarly at higher frequencies.

Unconstrained half-layer SVT-L0 model – mode couplings



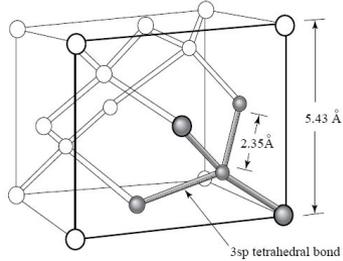
Rigid motions

Several modes in the 1 kHz bandwidth

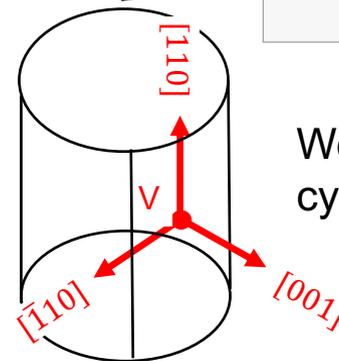
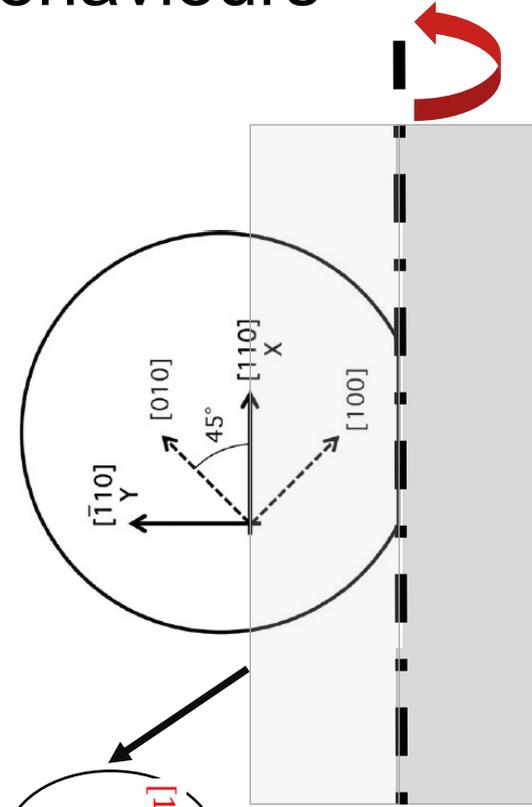
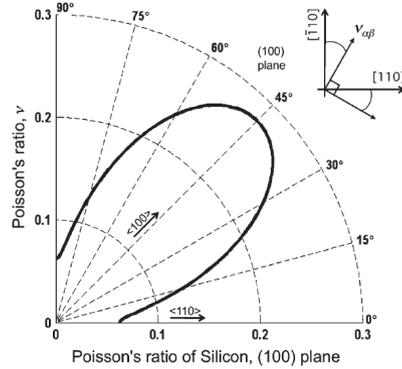
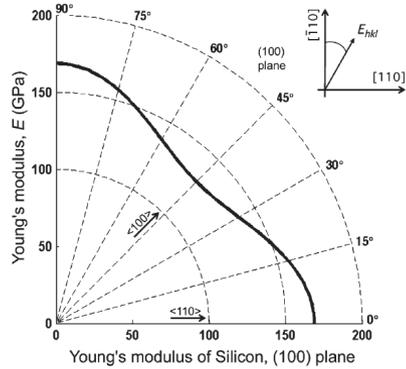
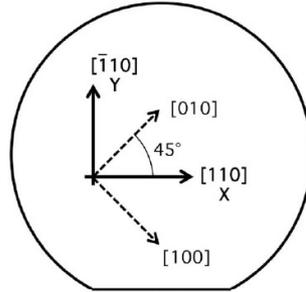
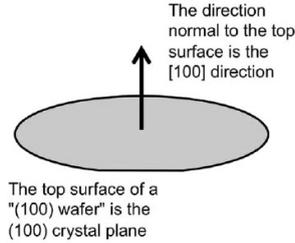
Carbon foam structures (longerons and half rings) have modes very close to the vibration of the silicon shell.

Silicon anisotropic behaviours

c-Si



Typical c-Si $\langle 100 \rangle$



We must define a local cylindrical coordinate system.

A proper rotation of the elasticity matrix should be considered in the vibrational simulations.

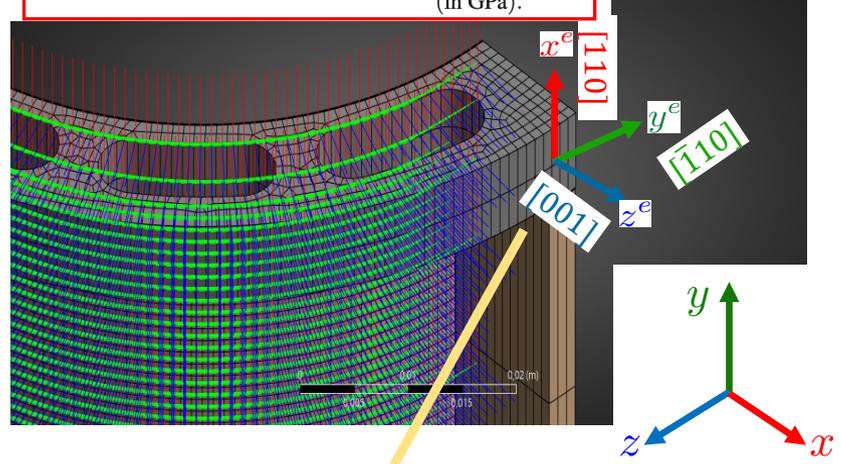
Setting the silicon anisotropic behaviours

$$\begin{aligned}
 & E_x = E_y = E_{110} = 169 \text{ GPa} & E_z = E_{100} = 130 \text{ GPa} \\
 & \nu_{yz} = 0.36 & \nu_{zx} = 0.28 & \nu_{xy} = 0.064 \\
 & G_{yz} = G_{zx} = 79.6 \text{ GPa} & G_{xy} = 50.9 \text{ GPa}
 \end{aligned}$$

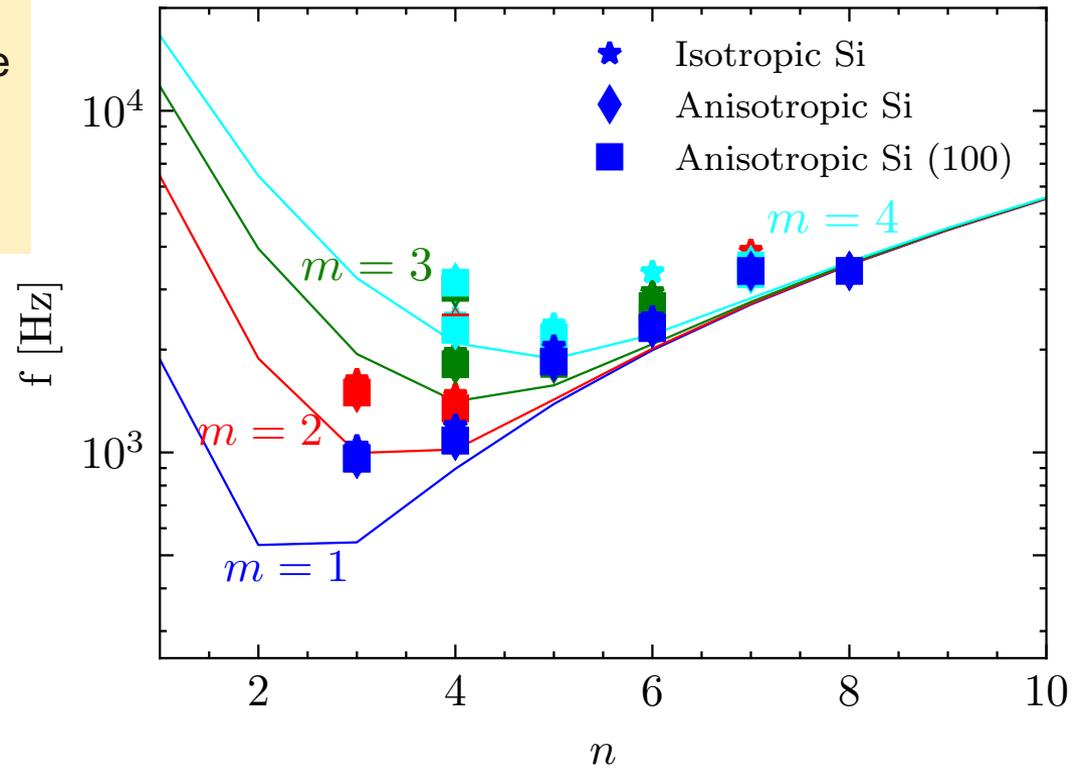
$$\begin{bmatrix} \sigma_1 \\ \sigma_2 \\ \sigma_3 \\ \sigma_4 \\ \sigma_5 \\ \sigma_6 \end{bmatrix} = \begin{bmatrix} 194.5 & 35.7 & 64.1 & 0 & 0 & 0 \\ 35.7 & 194.5 & 64.1 & 0 & 0 & 0 \\ 64.1 & 64.1 & 165.7 & 0 & 0 & 0 \\ 0 & 0 & 0 & 79.6 & 0 & 0 \\ 0 & 0 & 0 & 0 & 79.6 & 0 \\ 0 & 0 & 0 & 0 & 0 & 50.9 \end{bmatrix} \begin{bmatrix} \varepsilon_1 \\ \varepsilon_2 \\ \varepsilon_3 \\ \varepsilon_4 \\ \varepsilon_5 \\ \varepsilon_6 \end{bmatrix}$$

(in GPa).

c-Si elasticity matrix in the frame of reference of a standard $\langle 100 \rangle$ silicon wafer



Element coordinate system for the correct representation of the orthotropic behaviours of the c-Si shell layer.



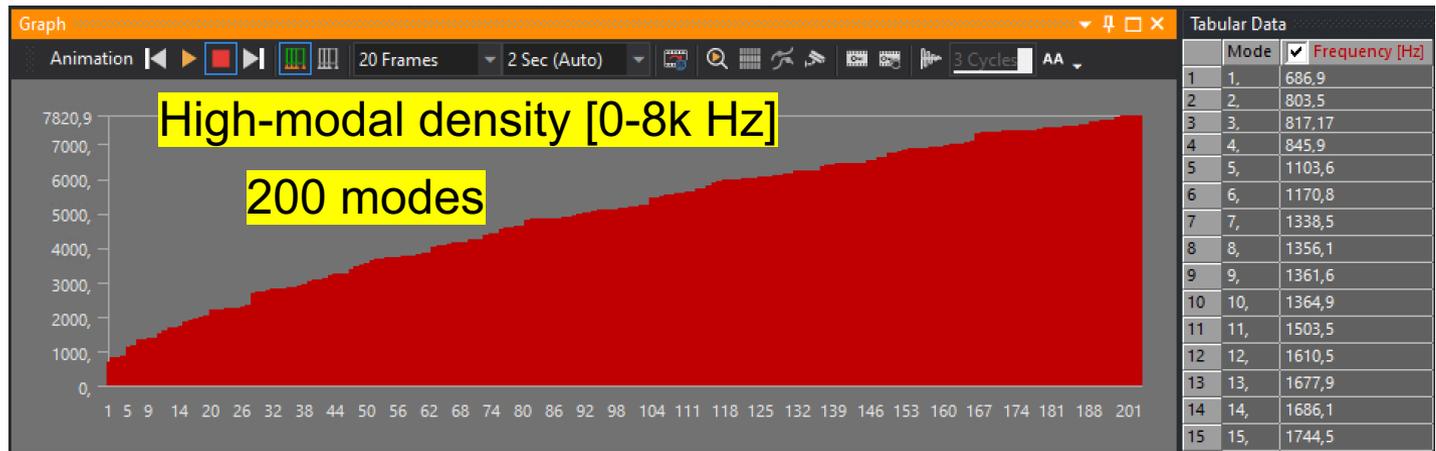
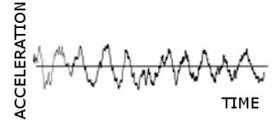
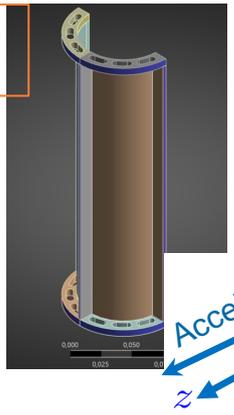
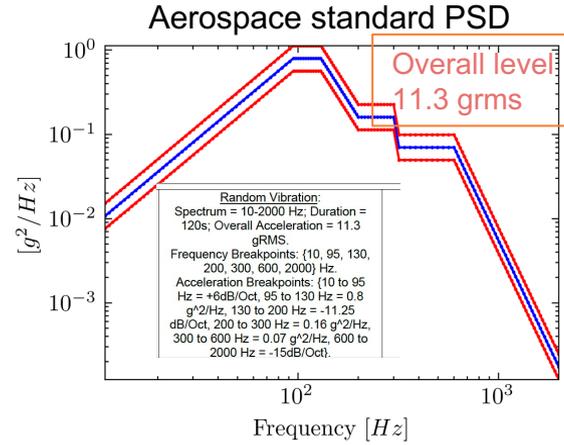
Frequencies are shifted by 10-100 Hz w.r.t. isotropic case

Random vibration test of the SVT-L0 model

Ansys WB Workflow

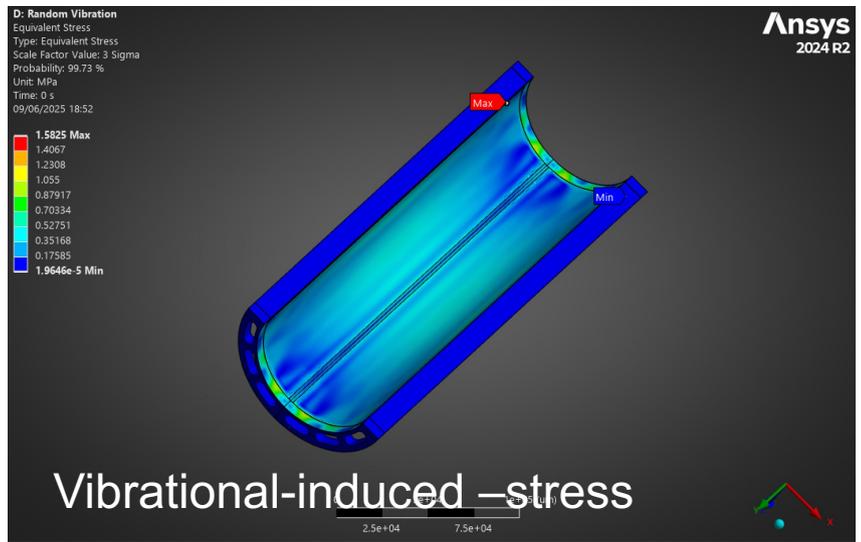
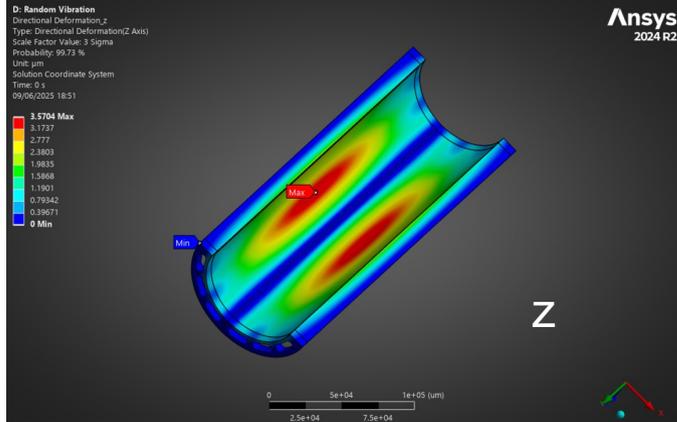
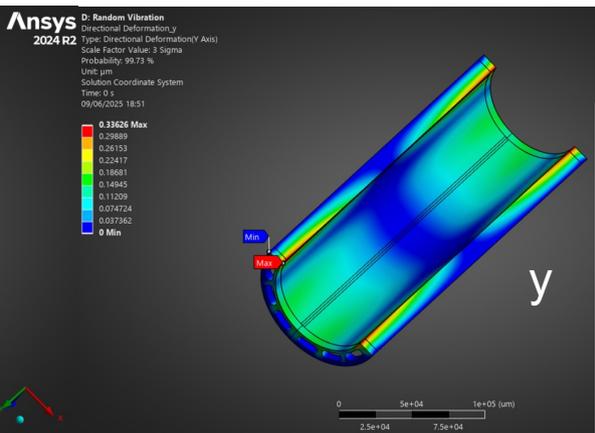
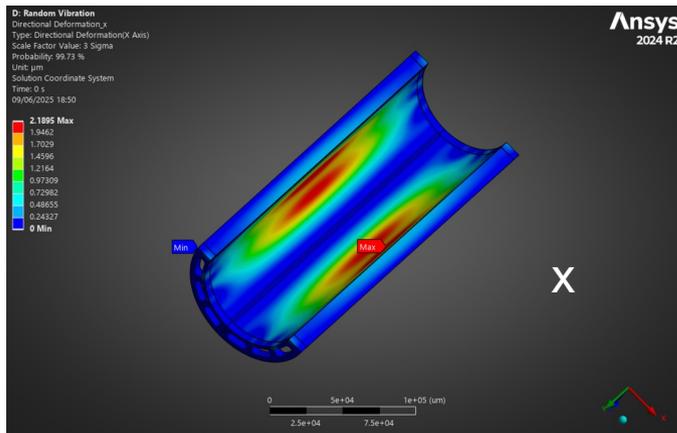


Participation factor in X,Y,Z 64% , 86%, 72% to have a good representation of the dynamics of the system.



PSD spectrum used for vibrational tests with electronic equipment in the aerospace industry

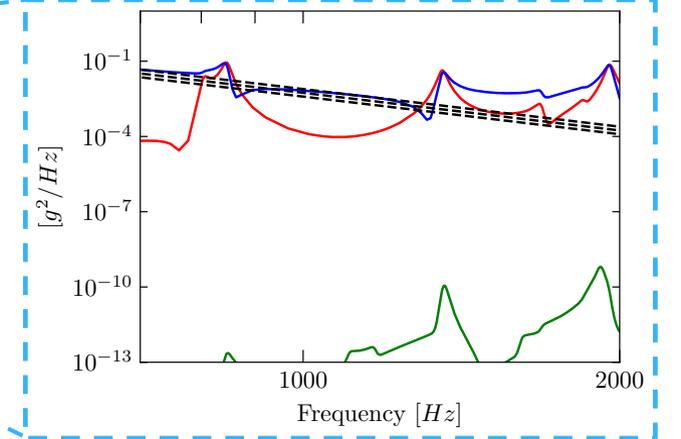
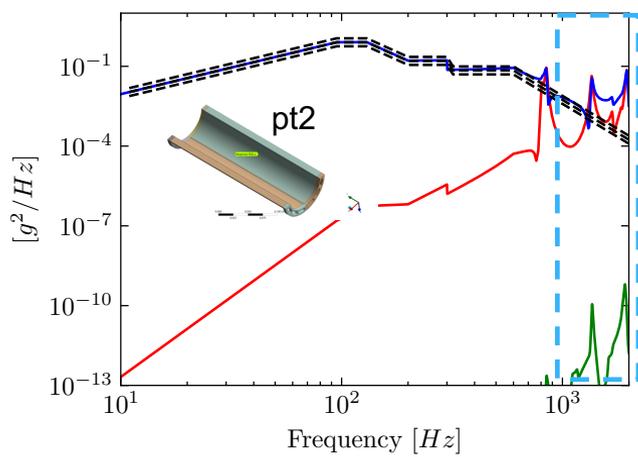
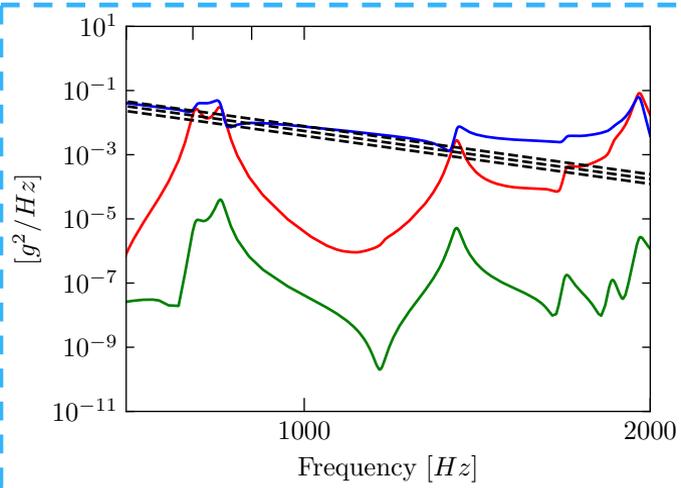
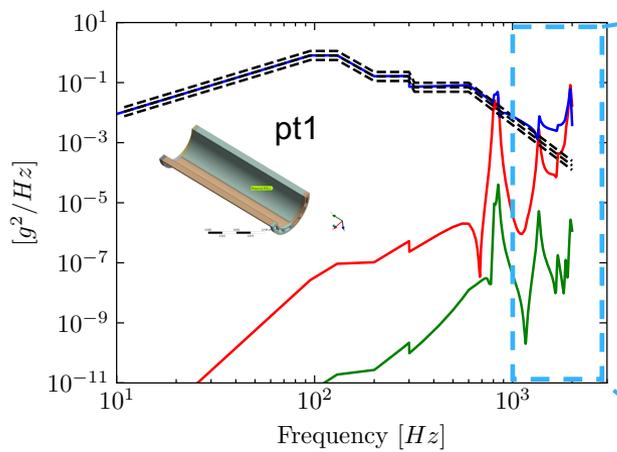
Directional deformation & stress



RMS displacement (maximum/averaged)		
u_x		2.19 μm
\bar{u}_x		0.69 μm
u_y		330 nm
\bar{u}_y		78 nm
u_z		3.57 μm
\bar{u}_z		1.51 μm

Vibrational-induced stress

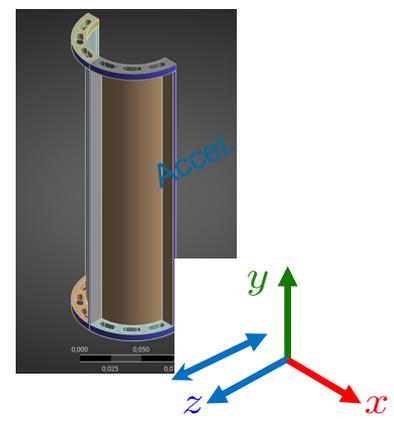
Acceleration in two control points



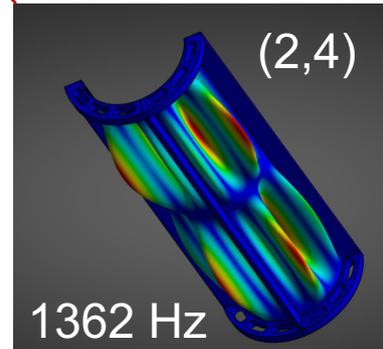
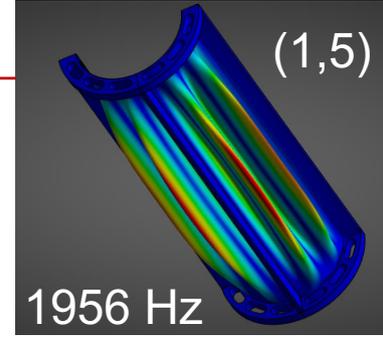
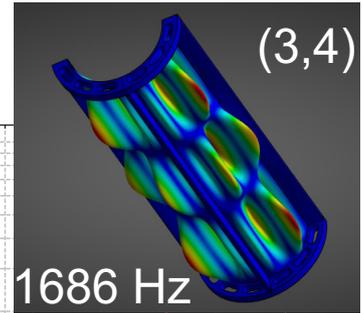
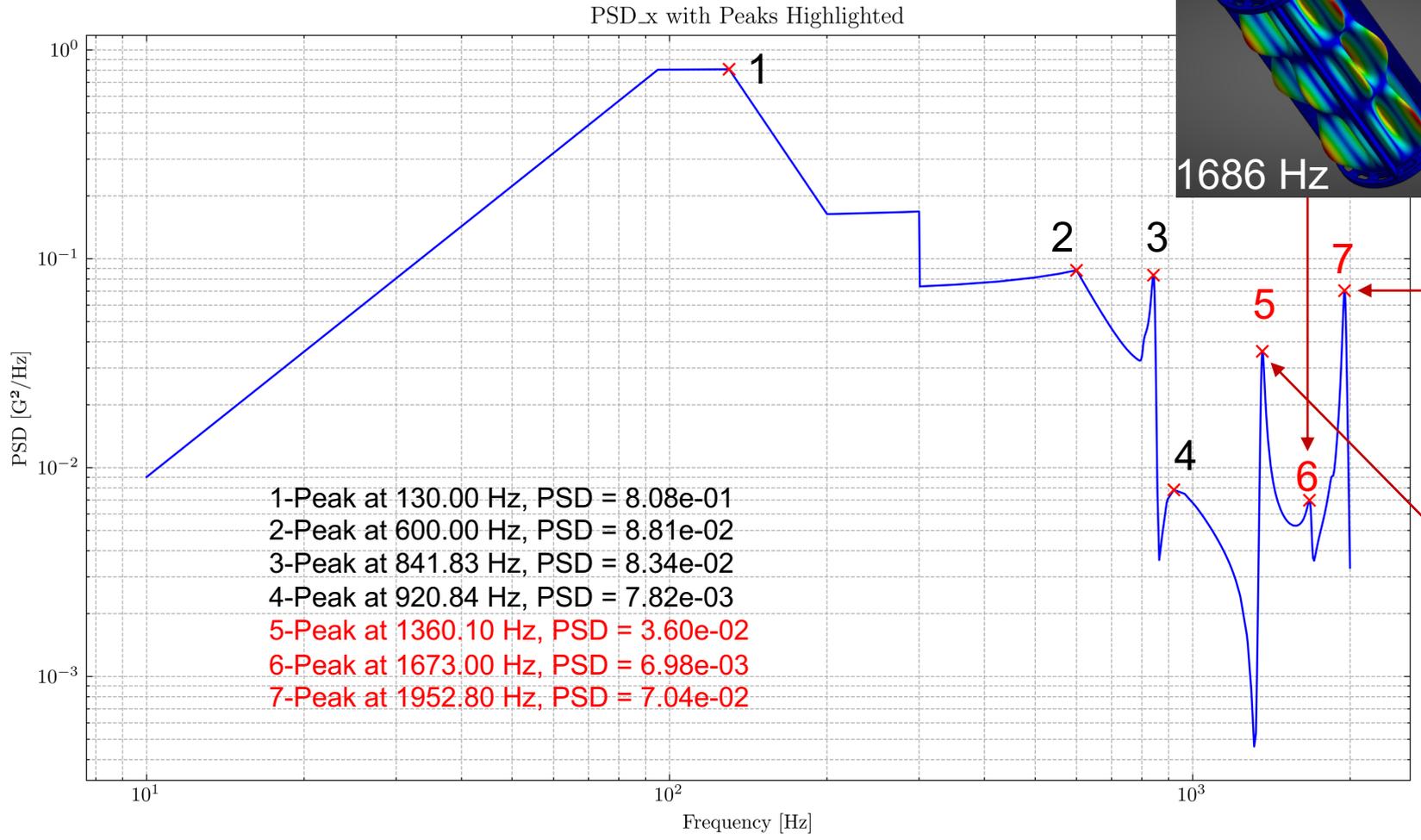
Critical damping

$$\zeta = 1\%$$

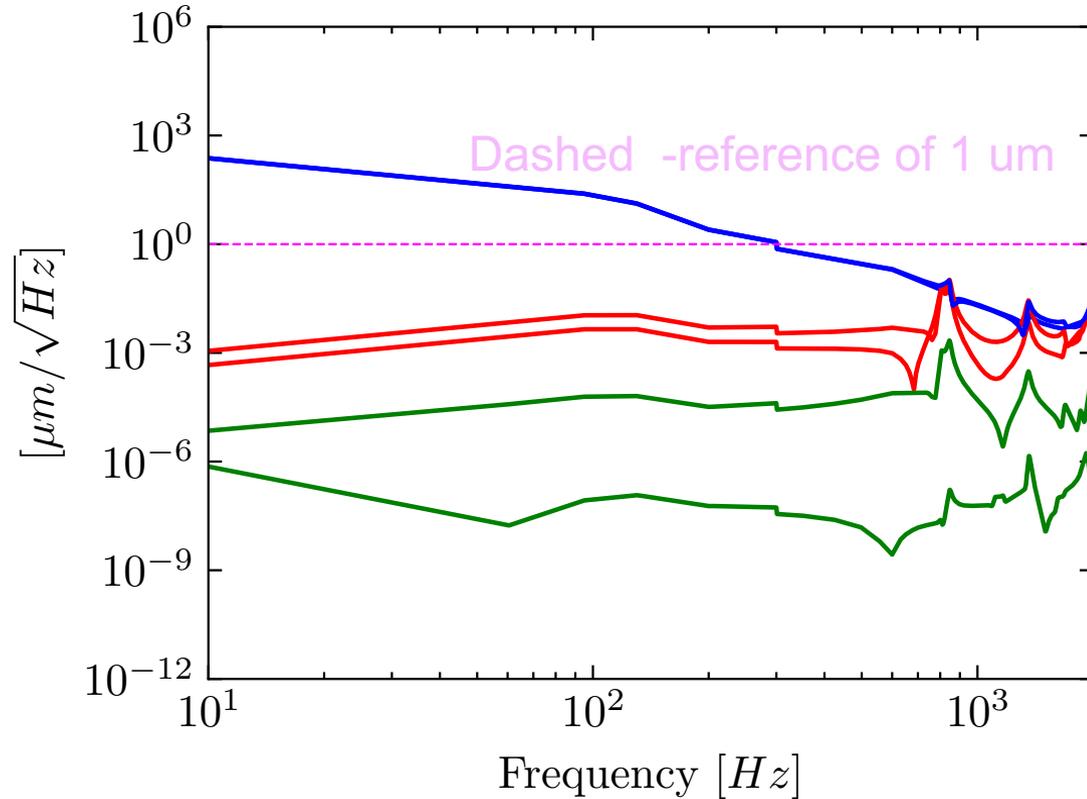
$$Q = \frac{1}{2\zeta} = 50$$



$$\text{PSD}_{g^2/\text{Hz}} = \frac{\text{PSD}_{(m/s^2)^2/\text{Hz}}}{9.81^2}$$

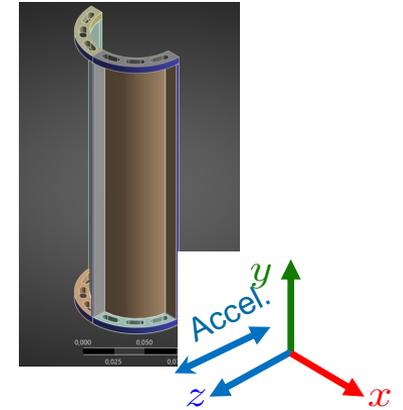
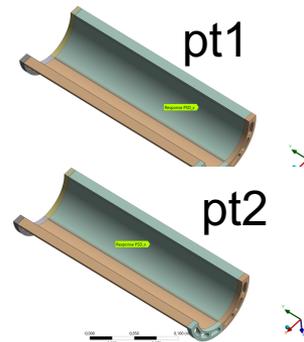


Displacement ASD



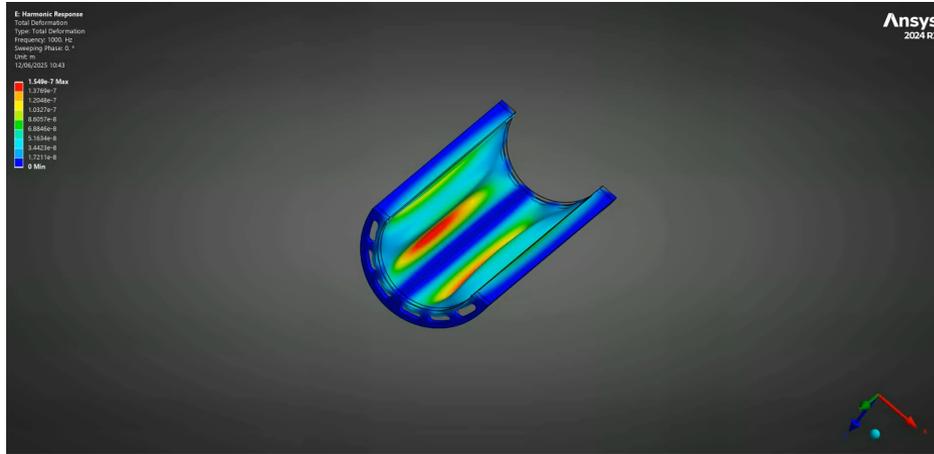
$$\zeta = 1\%$$

$$Q = \frac{1}{2\zeta} = 50$$



The system already developed appears to withstand severe random vibrational test.

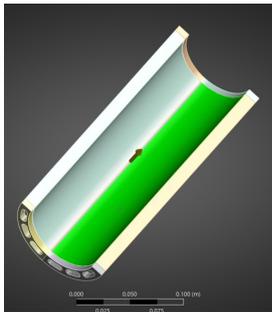
Harmonic Analysis at 1g excitation



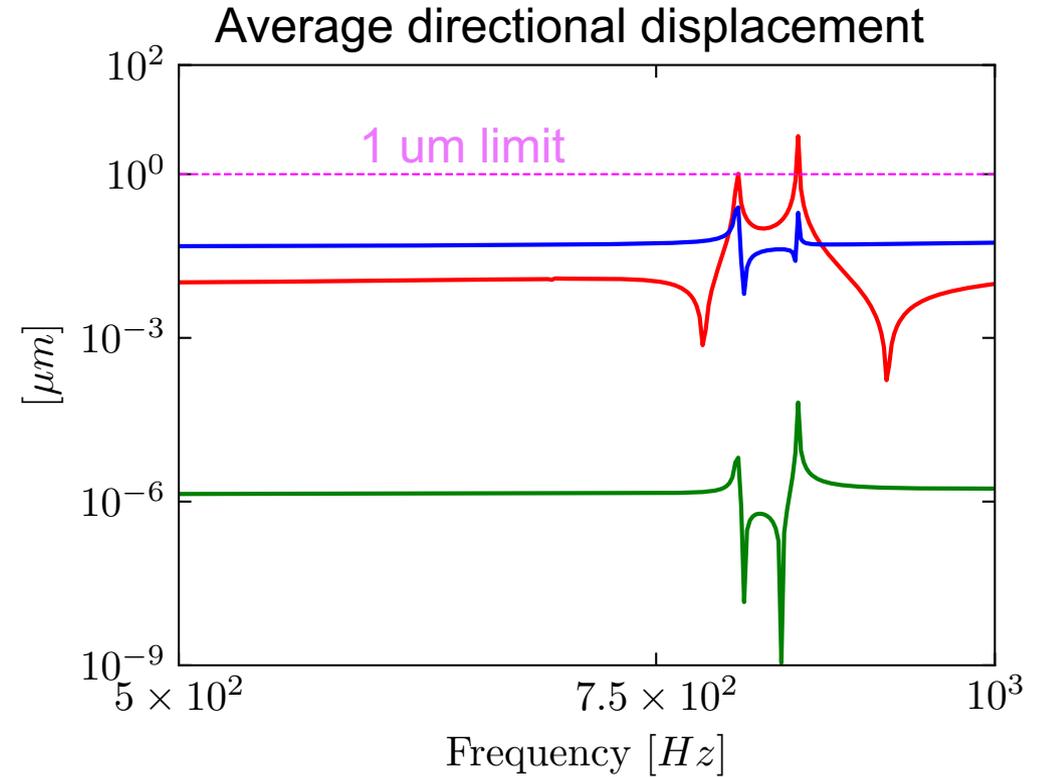
Acceleration 1g along Z axis

$$\zeta = 1\%$$

$$Q = \frac{1}{2\zeta} = 50$$



Reference surface for evaluating the average displacement



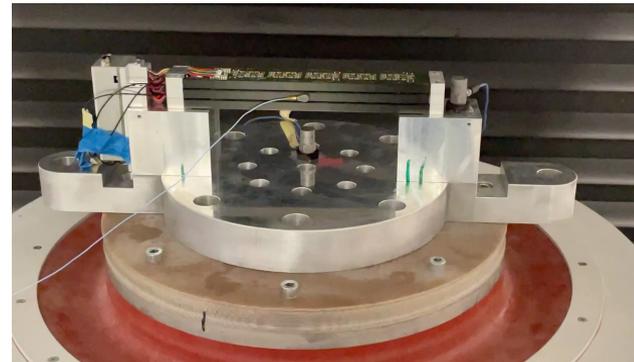
Conclusions

- **We have developed a modelling strategy** to analyse the vibrational behaviour of thin silicon shell structures for the Silicon Vertex Tracker (SVT).
- **We have validated the Finite Element Method (FEM) modal analysis** against analytical models to ensure high accuracy and reliability of the simulations.
- **We have perform a first FEM random vibrational** test with PSD aerospace spectrum to assess the structural integrity and mechanical resilience of the silicon shells under severe transport conditions.

- **Developing a FEM-based model of the whole SVT apparatus** for estimating the displacement noise in the Si sensors due to multiple sources of vibrations (air-flow, seismic/cultural, thermal)
- **Configuring a dedicated experimental apparatus** for performing extensive vibrational tests at PROM facility in Trento

[Pro]^M 

<https://promfacility.eu> Trento

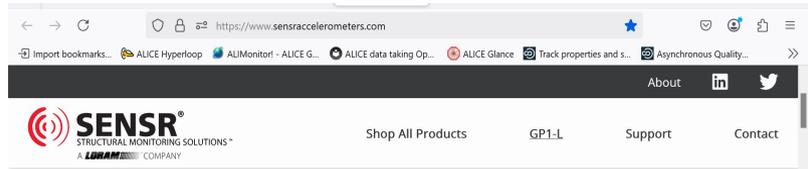


Vibrational test of ALPIDE sensors mounted on a CFRPs stove.

Thank you for your attention!

Back-up slides

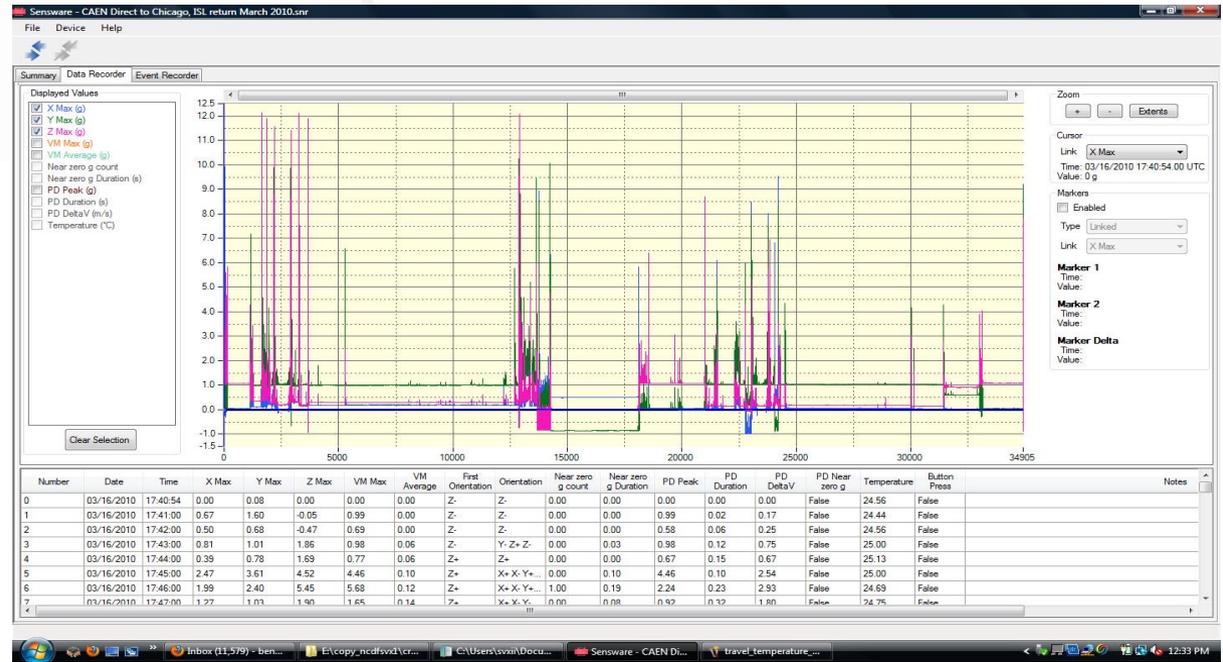
Lessons learned from the CDF Silicon Detector experience



\$899

Transportation in the US

Acceleration >11g but commercial flight 2.5 g



Courtesy from dr. Benedetto di Ruzza

Seismic noise (Miles' formula)

The RMS acceleration response of an SDOF system to a white noise input is given by:

$$G_{RMS} = \sqrt{\frac{\pi}{2} f_n Q \cdot ASD_{input}}$$

Where:

- G_{RMS} : Root Mean Square acceleration (e.g., in g_{RMS} or m/s^2_{RMS})
- f_n : Natural frequency of the SDOF system (in Hz)
- Q : Quality factor, representing the amplification at resonance. It is related to the damping ratio (ζ) by $Q = \frac{1}{2\zeta}$.
- ASD_{input} : Input Acceleration Spectral Density (e.g., in g^2/Hz or $(m/s^2)^2/Hz$). For white noise between f_1 and f_2 , this is the constant value of the PSD within that band, assuming f_n is within this range.
- Y_{RMS} : Root Mean Square displacement (e.g., in $inches_{RMS}$ or $meters_{RMS}$)
- All other terms are as defined for the acceleration formula.

Note on Units: If ASD_{input} is provided in g^2/Hz , the calculated G_{RMS} will be in g_{RMS} . To obtain Y_{RMS} in meters, G_{RMS} must first be converted to m/s^2 using the standard acceleration due to gravity ($g_N \approx 9.80665 m/s^2$). If ASD_{input} is already in $(m/s^2)^2/Hz$, then Y_{RMS} will directly be in meters.

Applying this relationship to the RMS acceleration formula, the RMS displacement (Y_{RMS}) is:

$$Y_{RMS} = \frac{G_{RMS}}{(2\pi f_n)^2}$$

Substituting the expression for G_{RMS} :

$$Y_{RMS} = \frac{1}{(2\pi f_n)^2} \sqrt{\frac{\pi}{2} f_n Q \cdot ASD_{input}}$$

This expression can be simplified to:

$$Y_{RMS} = \sqrt{\frac{Q \cdot ASD_{input}}{32\pi^3 f_n^3}}$$

Two insulated modes

$$f_0 = 55.74 Hz / f_0 = 686.9 Hz$$

$$ASD = 1.61 \times 10^{-8} g_N^2 / Hz \quad Q = 20$$

$$\delta_{RMS} = 424.52 [nm] / \delta_{RMS} = 9.812 [nm]$$

External (seismic) acceleration levels observed typically inside stationary particle physics experiments are low 10^{-14} - 10^{-16} [$m^4/s^2/Hz$] in [0.1 -100] Hz.

GW detectors' seismic noise

